PHYS-E0525 Microscopy of Nanomaterials P (5 cr)

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First lecture 26.1. 2021

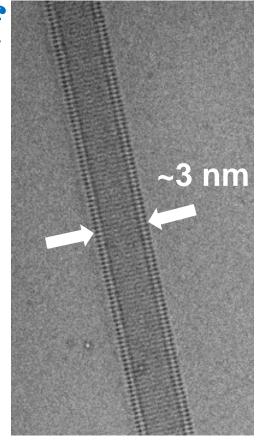
Tuesday 12.15 - 14

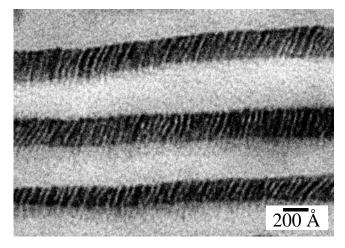
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Course overview:

The course gives basic knowledge of the microscopy of materials nanoscale structures - including soft and hard materials. Lectures will concentrate on transmission electron microscopy (TEM, STEM): high resolution imaging, electron diffraction and analytical microscopy by using elemental analyses (EDX, EELS), cryo-electron microscopy and 3D electron tomography. Additionally, scanning electron microscopy (SEM and FIB), atomic force microscopy (AFM) and methods to prepare samples are lectured..

Course Registration: WebOodi





Lectures:

Prof. Janne Ruokolainen, Dr. Hua Jiang, Dr. Jani Seitsonen, Dr. Ramzy Abdelaziz, Prof. Peter Liljeroth, Dr. Lide Yao

Ten	tative	Sch	edule
	ialive		Cuuic

- 26. 1. Introduction & Nanomicroscopy center (JR)
- 2. 2. SEM (Ramzy)
- 9. 2. TEM Basics 1 (JR)
- 16. 2. TEM Basics 2 and Cryo-TEM (JR)
- 23. 2. no lecture (exam period at Aalto)
- 2. 3. Advanced TEM 1 (Hua)
- 9. 3. Advanced TEM 2 (Hua)
- 16. 3. Advanced TEM 3 (Hua)
- 23. 3. AFM (Peter or Ville)
- 30. 3. 3D-TEM-Tomography (Jani)
- 6. 4. FIB and Sample preparation (Lide)

Summary:

Intro, Basic TEM, Cryo TEM ~ 3 lectures

Advanced TEM 3 lectures

(High resolution TEM and STEM,

diffraction, spectroscopy EDX, EELS)

AFM

FIB/sample preparation

SEM

Tomography

Additional Literature: (optional)

Book 1: Transmission electron microscopy

Basics I (David William and Barry Carter)

2nd edition

Book 2: G.H. Michler "Electron microscopy

of polymers" (TEM, SEM, AFM..)

Book 3: A practical Guide to Tramsmission Electron Microscopy (Zhiping Luo)

Additional Literature if you are interested to study more in this topic..

Book 1: Transmission electron microscopy Basics Part I (David William and Barry Carter) 2nd edition

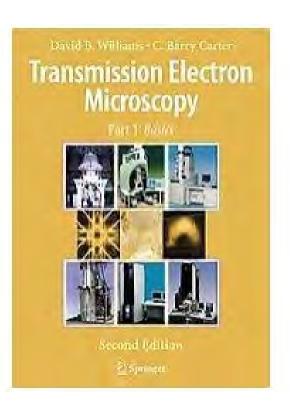
This book has *more theory* and it also has lots of technical information about microscope (vacuum systems, electron sources, sample holders etc..) and it also has 3 other books for Advanced TEM (Part 2: Diffraction, Part 3: high resolution imaging and Part 4: Spectroscopy)

Book 2: G.H. Michler "Electron microscopy of polymers" (TEM, SEM, AFM..)
A bit easier book to study – more practical and has also SEM and AFM parts (First 250 pages are useful – rest are specific polymer applications..)

Book 3: A practical Guide to Transmission Electron Microscopy (Zhiping Luo)
This book is most practical especially those who want to learn how to operate
microscopes Chapter 1-3 and (partly chapter 5?) and chapters 7-9. (chapters 4, 5, and
6 are diffraction and perhaps more advanced level than this course..)

Transmission Electron Microscopy A Textbook for Materials Science David B. Williams, C. Barry Carter

Tl	e Transmission Electron Microscope
\mathbf{C}	apter Preview
1.	What Materials Should We Study in the TEM?
1	Why Use Electrons?
	1.2.A An Extremely Brief History
	1.2.B Microscopy and the Concept of Resolution
	1.2.C Interaction of Electrons with Matter
	1.2.D Depth of Field and Depth of focus
	1.2.E Diffraction
1.	Limitations of the TEM
	1.3.A Sampling
	1.3.B Interpreting Transmission Images
	1.3.C Electron Beam Damage and Safety
	1.3.D Specimen Preparation
1.	Different Kinds of TEMs
1.	Some Fundamental Properties of Electrons
1.	Microscopy on the Internet/World Wide Web
	1.6.A Microscopy and Analysis-Related Web Sites
	1.6.B Microscopy and Analysis Software
Cl	apter Summary



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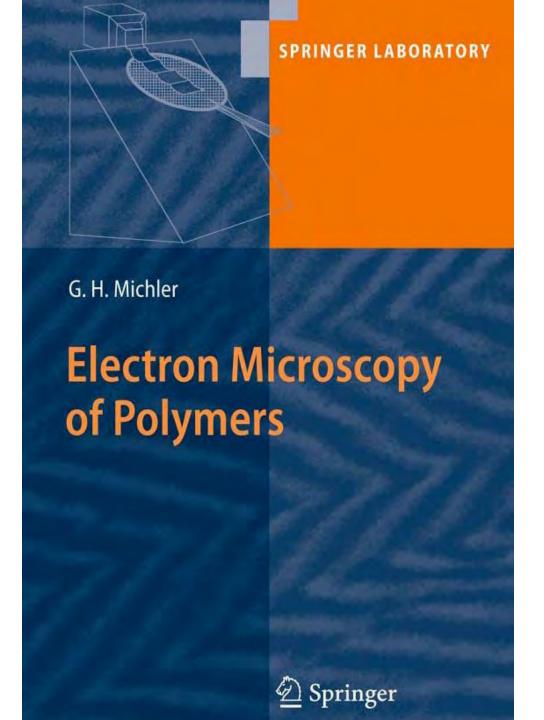
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Part II in this book is mainly soft materials sample preparation – i.e. quite useful for many of you

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Part III in this book is special applications for polymers – i.e. not the topic of this course..

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PHYS-E0526 Microscopy of Nanomaterials, laboratory course P (5 cr)

Assistant: Shandilay Shruti and other teachers: Dr. Jani Seitsonen (TEM & Tomography), Dr. Hua Jiang (HR-TEM), Dr. Ramzy Abdelaziz (SEM), Dr. Lide Yao (FIB), DR. Ville Liljeström (AFM)

As practical exercises nanostructured materials are studied with various microscopy methods. Course includes practical microscopy exercises by using transmission electron microscopy (TEM), scanning electron microscopy (SEM) and Focused ion beam (FIB).

Number of students participating to the course will be limited. (max. ~18) Based on applications... nmc-contact-sci@aalto.fi Deadline 16. 2. 2020

Basic exercises – Demos: (4? persons per group):

- 1) High resolution TEM (Jeol 2200FS Cs-corrected TEM)
- 2) 3D tomography data collection (Jeol 3200FSC liquid helium cryo TEM or Jeol2800) + Tomography data processing (Computer room)

Small group exercises: (Select 2) (2? persons per group)

- 1) basic-TEM imaging
- 2) SEM imaging or FIB -SEM processing/imaging
- 3) AFM

Independent Small group exercises (without supervision.. 2? person per group)

(2 exercises)

- 1) TEM imaging
- 2) SEM imaging
- 3) ...

To apply for the Laboratory Course - Send the following information by email: nmc-contact-sci@aalto.fi deadline 16. 2. 2020

1. You are a *		
graduate student		
exchange student		
Ph.D student		
post doc/other		
2. Your primary affiliation is *		
Aalto University		
 University of Helsinki 		
○ VTT		
Other		
3. Do you belong to a research gr	oup? If yes, who is your supervis	or/instructor?
Research Group		
Supervisor/Instructor		
4. Write with your own words you	ur primary motivation to participa	ate on the laboratory course. *
you our more you	primary insuration to participa	
5 What is a town and do not a long to	i	
5. What instrument do you plan t	o use in your research?	
☐ AFM		
☐ SEM		
□ TEM		
HRTEM		
Cryo-TEM		
TEM tomography		
□ XRAY		
6. Contact Information		
Firstname *		
Lastname *		
Email *		
Chudant Number (if you have one)		

Exam for lecture course PHYS-E0525 Microscopy of Nanomaterials... We have multiple choice questions from TEM, SEM, FIB, AFM etc.. + normal questions – where you write short answers

TEM Questions

1. What is STEM?

- Scanning transmission electron microscopy
- Standard transmission electron microscopy
- Scanning and transmission electron microscopy
- Suitable transmission electron microscopy
- Scanning tunneling electron microscopy

2. Bright field TEM is best described as?

- o Microscopy where the electron beam is well aligned
- The exclusion of the scattered electron beam while the beam is directed onto the sample
- Any imaging that must be undertaken in a well lit room
- The exclusion of the central beam electrons by tilting the beam, displacing the objective aperture or introducing the beam stop
- Microscopy where the filament has not broken

3. How can chromatic aberrations be minimized in a TEM?

- Use an electron gun with high energy spread and a thin specimen
- o Use an electron gun with low energy spread and a thick specimen
- o Use an electron gun with high energy spread and a thick specimen
- o Use an electron gun with medium energy spread and a thick specimen
- Use an electron gun with low energy spread and a thin specimen



Nanomicroscopy center

Prof. Janne Ruokolainen (Director Jani Seitsonen 1. 1. 2021 →)
Aalto University, Otanano





Nanomicroscopy Center?



Introduction

The new Nanomicroscopy Center is large microscopy clusters (even compared to other European centers). The center is now housing various microscopes able to characterize hard materials down to atomic resolution, and soft materials including biomaterials down to molecular resolution.

- Started in operation 2008 →
- Center area 1220 m² / 740 m²
- Center for various different *high resolution microscopy* techniques (currently >10 different high-resolution microscopes: 5 TEM's, 3 SEM's, AFM's, 3 STM's.. + New FIB-SEM 2019
- Instrument investments (until now..) >10 M€

Key Instruments:

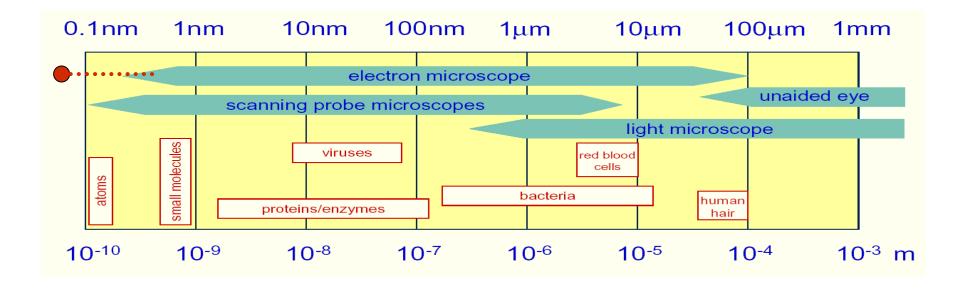
- First lens *aberration corrected* transmission electron microscope in Finland with approximately 1 Å resolution (*JEOL 2200FS*)
- First *Liquid helium cryo*-transmission electron microscope in Finland (operating at -255 °C or -187 °C) (*JEOL 3200FSC*)

Equipment and their new values, and purchase years

• •	•	•
Transmission electron microscopes (TEM)	Value	Year
1) 120kV TEM Tecnai 12	350 k€	2004
2) Double Cs corrected sub-Ångstrom 200kV (S)TEM, EDX, EELS	>2000 k€	2009
3) Liquid Helium 300kV cryo-TEM, EELS	>1500 k€	2009
4) 200kV FEG (S)TEM, EDX	>1000 k€	2016
5) 200kV FEG TEM (moved from Department of Materials Science and Engineering 2016)		
Scanning electron microscopes (SEM)		
1) JEOL 7500F FEG-SEM + EDX	400 k€	2008
2) Zeiss Sigma FEG-SEM	200 k€	2011
3) Zeiss E-SEM	150 k€	2011
4) dual beam FIB-SEM	~1000 k€	2019
Scanning probe microscopy (AFM, STM)		
1) Veeco Dimension 5000 AFM	300 k€	2008
2) RHK UHV-750 variable temperature STM (UHV-STM)	500 k€	2005 - 2009
3) Createc LT-STM low-temperature STM	460 k€	2012
4) cryo UHV-STM	580 k€	2012
X-ray Scattering		
1) Small Angle X-ray Scattering (SAXS)	550 k€	2006 - 2008
2) Wide and Medium Angle X-ray Scattering (WAXS/MAXS)	450 k€	2008 - 2016
3) 2D-microfocus XRD	500 k€	2016
4) New-SAXS small angle X-ray setup	500 k€	2020
sample preparation equipment etc.		
Cryo vitrification (3), ultra microtoming (2), ion-milling, polishing, plasma cleaner.		
TEM holders, cross section polisher,,	1000 k€	2009 -

Total: >12 M€

Microscopy Resolution – Different Microscopes

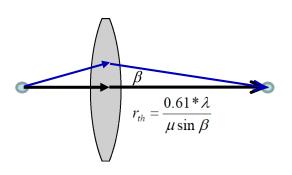


Nanoparticles, carbon nanotubes Lipids, polymer-amphiphile, liquid crystals Block copolymers Polymer blends, colloids... 0.1 nm – 1 – 5 nm 10 – 100 nm 50 nm – 10 μm

Electron microscope resolution:

In ideal case:

$$r_{th} = \frac{0.61 * \lambda}{\mu \sin \beta} \approx \frac{0.61 \lambda}{\beta}$$



Light microscope wavelenght ~ 400 - 600 nm Electron wavelenght $300 \text{ kV} \sim 0.002 \text{ nm} \text{ !!!}$

$$r_{sph} = C_s \beta^3$$

$$r_{chr} = C_c \frac{\Delta E}{E_0} \beta$$

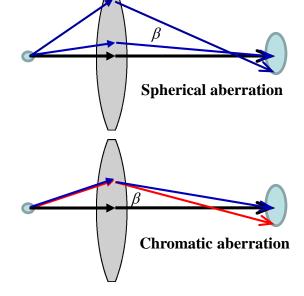


300 kV, Cs = 4.1 mm, Cc = 3.4 mm

→point resolution ~2.6 Å

Jeol 2200FS Cs = 1.0 mm Cc = 1.4 mm, 200kV Point resolution 2.3 Å (without Cs correctors)

Jeol 2800 200kV Cs = 0.7mm Point resolution 2.0 Å



$$r_{total} = \sqrt{(r_{th})^2 + (r_{sph})^2 + (r_{chr})^2 + \dots}$$

If spherical aberration could be corrected $Cs \sim 0 \rightarrow \text{resolution} < 1 \text{ Å}$

If also chromatic aberration could be corrected or minimized \rightarrow resolution < 0.5 Å

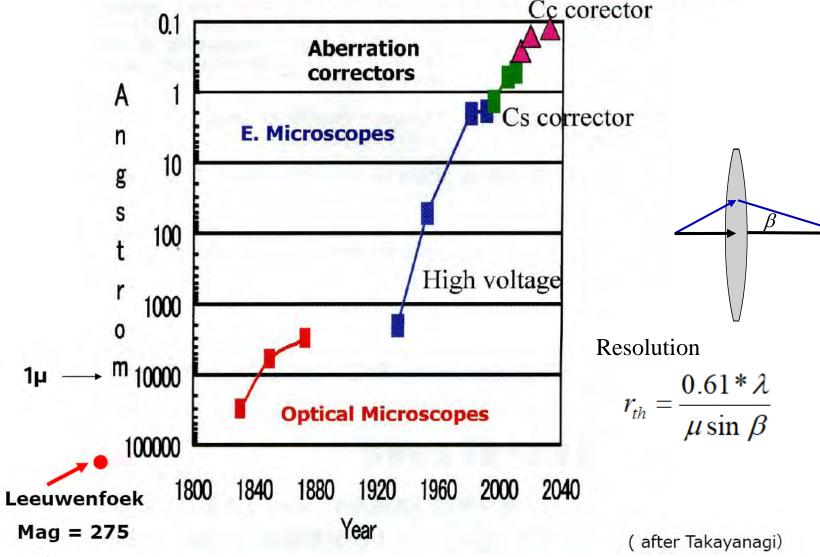
Spherical aberration in **Hubble Space Telescope**



Analysis of the flawed images showed that the cause of the problem was that the primary mirror had been ground to the wrong shape. Although it was probably the most precisely figured mirror ever made, with variations from the prescribed curve of only 10 nanometers, it was too flat at the edges by about 2200 nanometers (mirror diameter 2.4 meters..). This difference was catastrophic, introducing severe spherical aberration a flaw in which light reflecting off the edge of a mirror focuses on a different point from the light reflecting off its center.

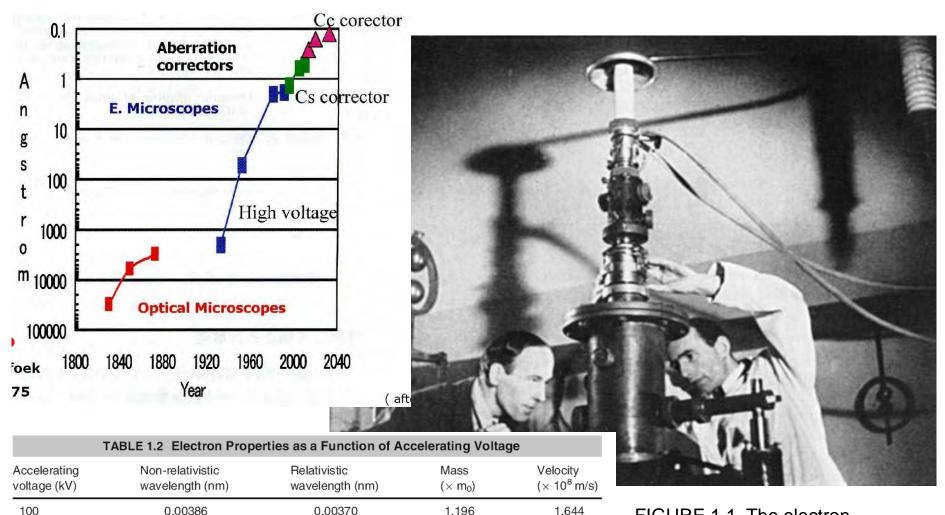
Progress of microscopes since 18 century

We stand now at a nanoworld of Q4 A (40pm)



Year 1676

Ernst Ruska and Max Knoll builtvthe first electron microscope in 1931 (Nobel Prize to Ruska in 1986)



1.235

1.391

1.587

1.783

2.957

1.759

2.086

2.330

2.484

2.823

0.00352

0.00273

0.00223

0.00193

0.00122

120

200

300

400

1000

0.00335

0.00251

0.00197

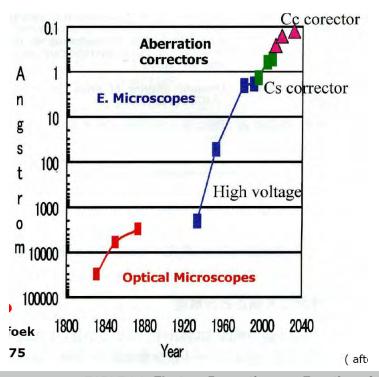
0.00164

0.00087

FIGURE 1.1. The electron microscope built by Ruska (in the lab coat) and Knoll, in Berlin in the early 1930s.

High voltage TEM (typically 400 kV -3 MV)

In early years the resolution was increased by using higher voltage TEM - since the wavelenght is smaller and therefore resolution is potentially better..



	ZIEGO.
	6441135
	MATERIAL STATES
е	
	Velocity

TABLE 1.2 Electron Properties as a Function of Accelerating Voltage				
Accelerating voltage (kV)	Non-relativistic wavelength (nm)	Relativistic wavelength (nm)	$\begin{array}{c} \text{Mass} \\ (\times m_0) \end{array}$	Velocity (× 10 ⁸ m/s)
100	0.00386	0.00370	1.196	1.644
120	0.00352	0.00335	1.235	1.759
200	0.00273	0.00251	1.391	2.086
300	0.00223	0.00197	1.587	2.330
400	0.00193	0.00164	1.783	2.484
1000	0.00122	0.00087	2.957	2.823

$$r_{th} = \frac{0.61 * \lambda}{\mu \sin \beta} \approx \frac{0.61 \lambda}{\beta}$$
 (in TEM β

(in TEM β is small)

Nowadays these high voltage TEM's are mostly used for material radiation damage research and some special applications where thick samples are required for imaging (high voltage electrons can penetrate thicker samples .. i.e even some micrometer thick samples .. Normal TEM's require typically <100 nm or even < 10 nm samples for high resolution work



Hitachi 3.5MeV (S)TEM

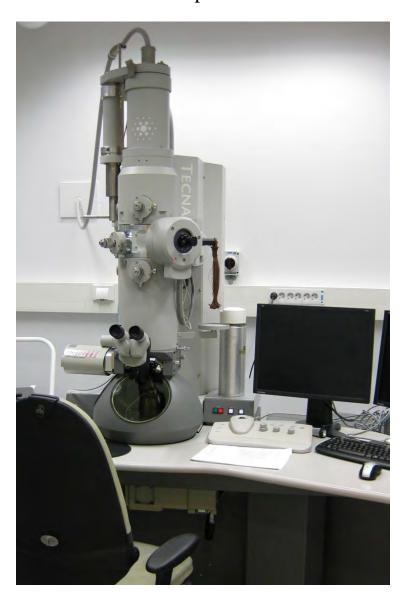


Microscopes are quite big - Notice the operator standing there..

Base F

In NMC we have 5 TEM's

In this picture the oldest TEM's 120 kV TEM and 200 kV TEM are shown



FEI Tecnai T12 Installation 2003



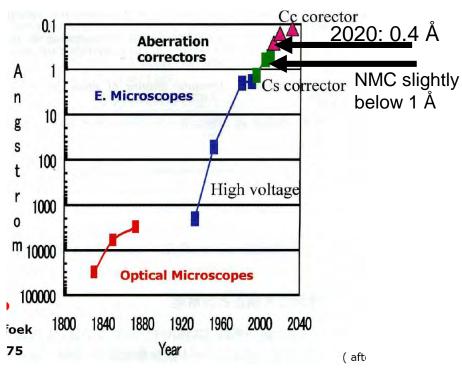
FEI Tecnai F20 Installation 1999? (Material science laboratory (Chem) and 2016 → moved to NMC)

NMC: new 200 kV TEM and 300 kV Cryo-TEM



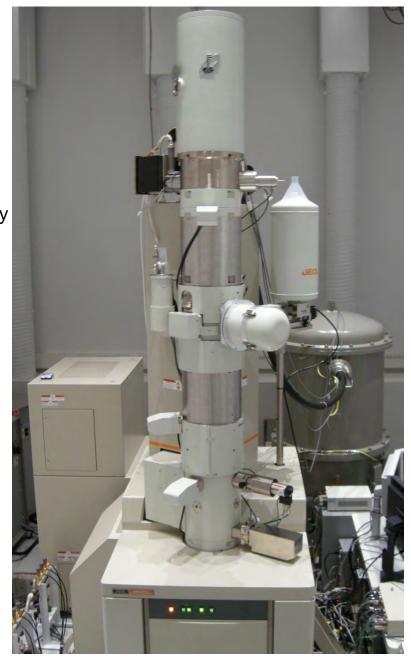


NMC highest resolution Double Cs-corrected (S)TEM

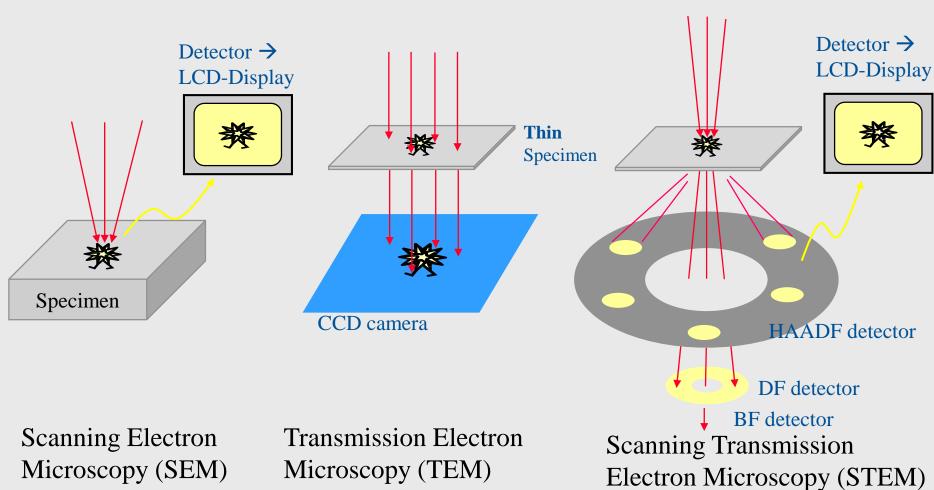


Installation 2009: TEM and STEM resolution slightly below 1 Å

Now best resolution for commercial microscopes is 0.4 Å



Brief introduction to the electron microscopy



Best resolution typically ~ 1 nm

Microscopy (TEM)

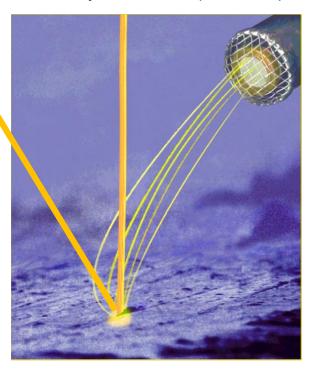
resolution ~ 2 Å (Cs corrected $\sim 0.5 - 1 \text{ Å}$)

resolution typically 1.3 Å (Cs corrected ~ 0.5 - 1 Å or even better)

Scanning Electron Microscopy (SEM)

Back scattering electron detector (high energy electrons)

Primary e-beam (1-30kV)



Secondary electron detector (low energy electrons)

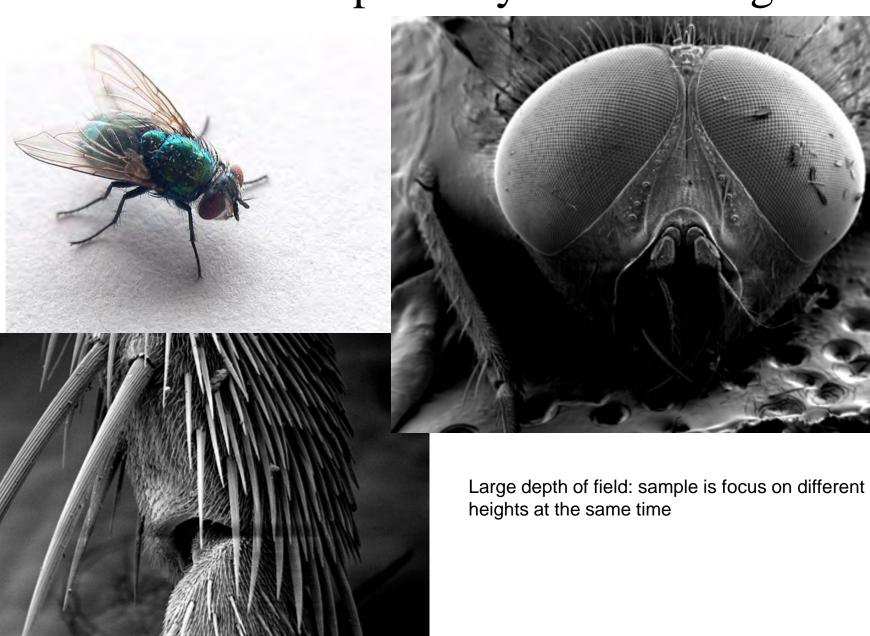
The scanning electron microscope (SEM) uses a focused beam of high-energy electrons (typically 1kV to 30 kV) to generate a variety of signals at the surface of solid specimens. The signals that derive from electron-sample interactions reveal information about the sample morphology (texture), chemical composition, and crystalline structure and orientation of the materials. Electron beam is scanned across the surface point by point and each point signal is collected, and 2-dimensional image is generated.

Scanning Electron Microscopy (SEM)

Surface technique:

- Relatively high resolution –
 Best case even <1nm (0.4 nm)
- Large depth of field (Large sample focus range)
- Low and high magnifications
- Large samples
- Possibility to microanalysis (EDX)
- Relatively easy sample preparation
 (normally thin metal coating needed gold/palladium, platinum, carbon, etc.)
- Samples in vacuum (same as TEM)
- Limited to surface studies (except if STEM option is available but then very thin samples needed... since voltage is max. 30 kV)

SEM examples: Fly head and leg





Nanomicroscopy center has 3 SEM's

1.) This SEM has been the primary training and research SEM at NMC since 2008.

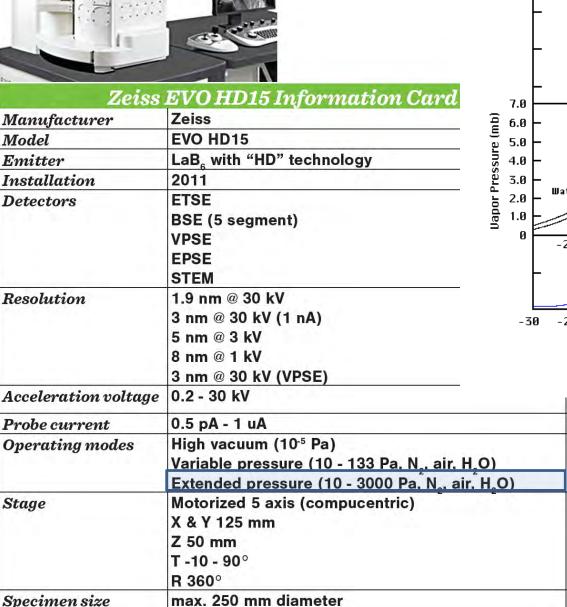
	JEOL JEOL		
	SM-7500FA Information Card		
Manufacturer	JEOL		
Model	JSM-7500F (later upgraded to JSM-7500FA)		
Emitter	Cold FEG		
Installation	2008		
Detectors	In-column SE ETSE BSE (2 segment) EDX (JEOL)		
Resolution	0.6 nm @ 30 kV 1.4 nm @ 1 kV		
Acceleration voltage	0.1 - 30 kV		
Probe current			
Operating modes	High vacuum (10 ⁻⁵ Pa)		
Stage	Motorized 5 axis (compucentric) X & Y 50 mm Z 25 mm T -5 - 70° R 360°		
Specimen size	max. 100 mm diameter max. 10 mm height		

This SEM is going to be the primary training SEM for Nanomicroscopy Center SEM users.

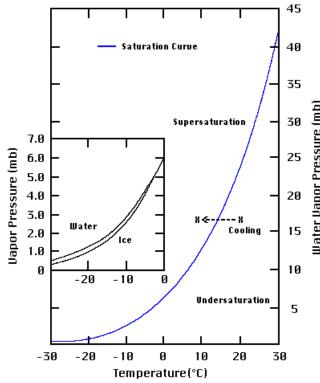
2.)

Jaga		ZEISS	
Zeiss	Sigma VP Information Co	urd	
Manufacturer	Zeiss		
Model	Σigma VP		
Emitter	Schottky FEG		
Installation	2011		
Detectors	In-column SE ETSE BSE (5 segment) VPSE STEM		
Resolution	1.3 nm @ 20 kV 2.8 nm @ 1 kV 2.5 nm @ 30 kV (VPSE)	_	
Acceleration voltage	0.1 - 30 kV		
Probe current	4 pA - 20 nA		
Operating modes	High vacuum (10 ⁻⁵ Pa)		
	Variable pressure (2 - 133 Pa, N ₂)	1	
Stage	Motorized 5 axis (compucentric) X & Y 125 mm Z 50 mm T -10 - 90° R 360°		
Specimen size	max. 250 mm diameter max. 145 mm height		

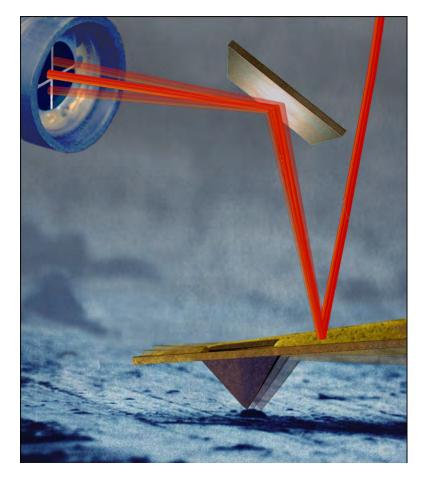
3.)



max. 145 mm height

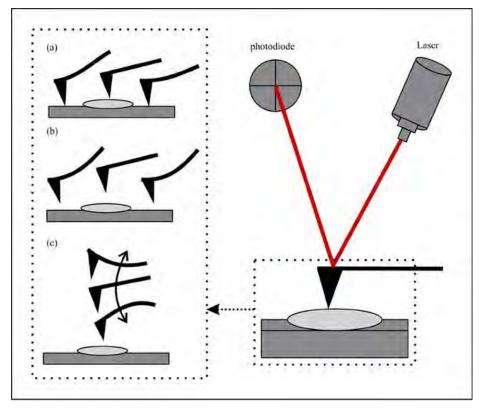


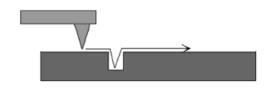
Scanning probe microscopy (SPM) historically called AFM)

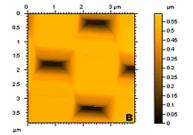


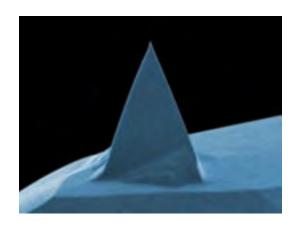
In AFM we use sharp tip to scan the sample surface to obtain information about surface topography and other properties (chemical, mechanical hardness, electrical etc.)

- a) Contact mode
- b) Non-contact mode
- c) Tapping mode (tip is oscillating on surface)



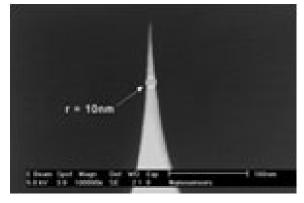




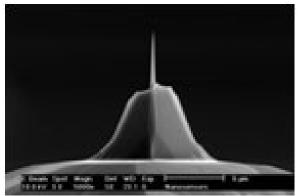


Examples AFM probes

Standard Tip radius typically 8-10 nm (cost 10 -20 euros per each)



Super sharp tips: Tip radius is typically 1nm (~100 €)





High aspect ratio tips: The length of the high aspect portion of the tip is larger than 1.5 µm

NMC instruments:

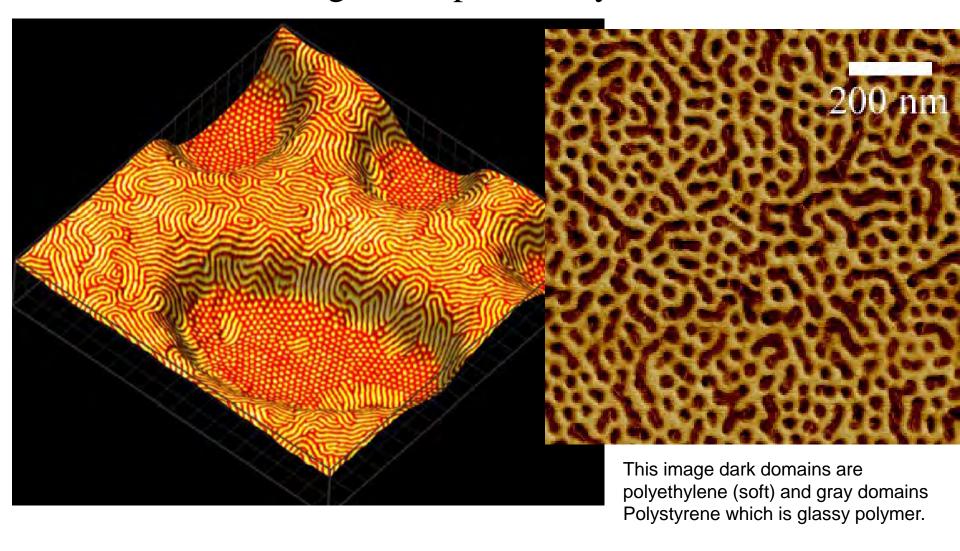
AFM: Veeco Dimension 5000 SPM (installed 1/2008)



- Originally designed for semiconductor imaging.
- Capable of loading samples up to 350 mm in diameter.
- Large scanning area ~90 x 90 μm.
- Automatic measurement for up to 100 preselected areas.
- High pixel-density image capture 5120 x
 5120 points.

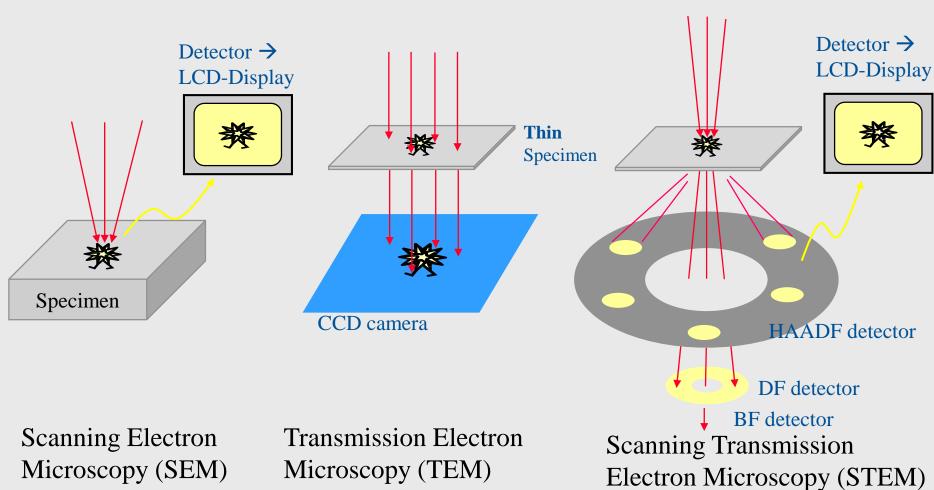
High resolution, easy to use, large samples..

AFM image examples - Polymer films:



Topography (height) and composition imaging (soft and hard domains) – in tapping mode imaging one can get at the same time the surface topographical information and contrast due to mechanical properties (example hard of soft domains)

Brief introduction to the electron microscopy

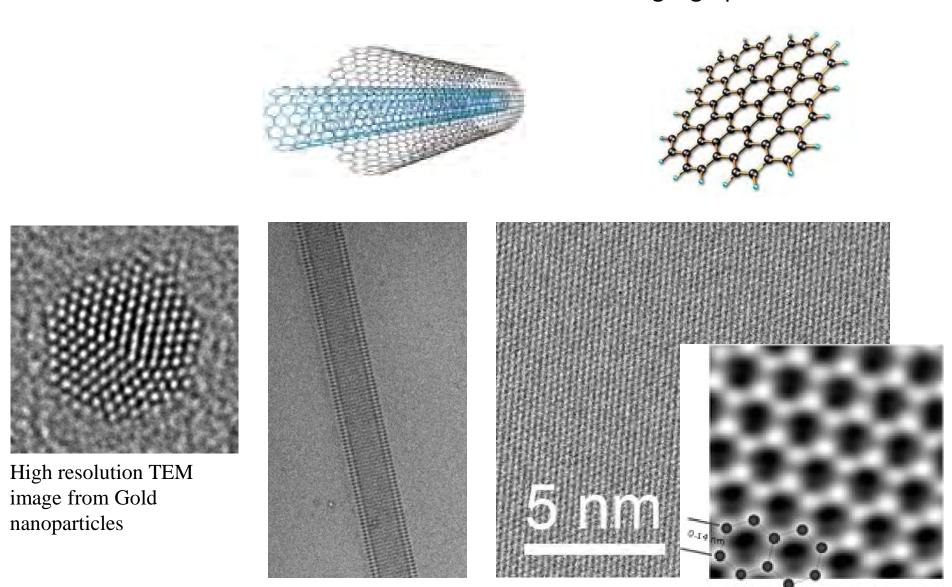


Best Practical resolution ~ 1 nm

Microscopy (TEM)

resolution ~ 2 Å (Cs corrected $\sim 0.5 - 1 \text{ Å}$)

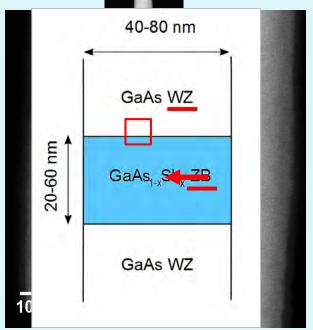
resolution typically 1.3 Å (Cs corrected ~ 0.5 - 1 Å or even better) Nowadays it is possible to obtain atomic resolution images even from low atomic number materials such as Carbon nanotubes and single graphene sheets..

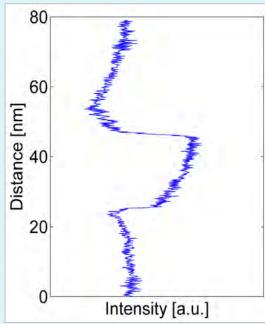


Another examples: Heterostructured GaAs nanowires

- GaAs nanowires (NWs)
- Molecular beam epitaxial (MBE) growth
- Pure GaAs NWs: Wurtzite (WZ) structure (纤锌矿结构, 六方相)
- Partially alloyed with Sb:
 GaAs_{1-x}Sb_x insert : Zinc bl

ZB) structure (闪锌矿结构,立方相)

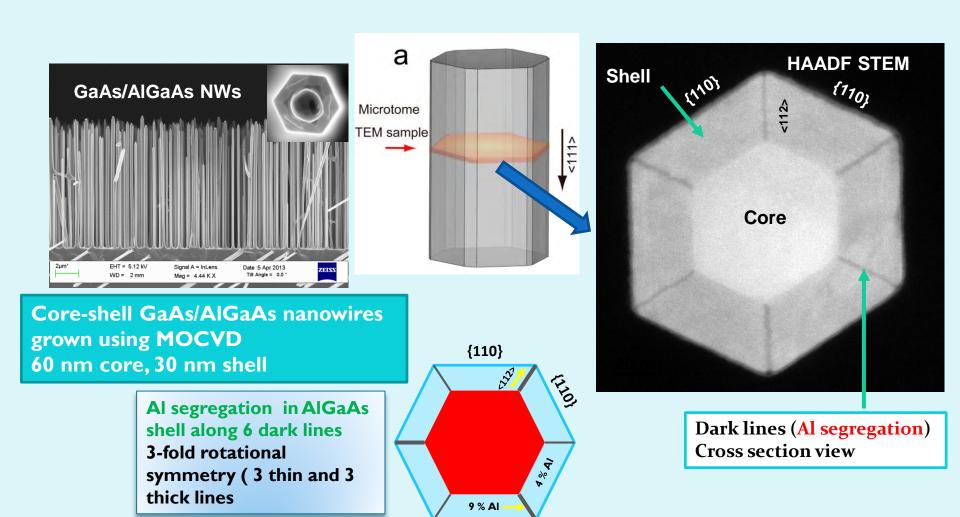




Sample: Hanne Kauko, NTUT



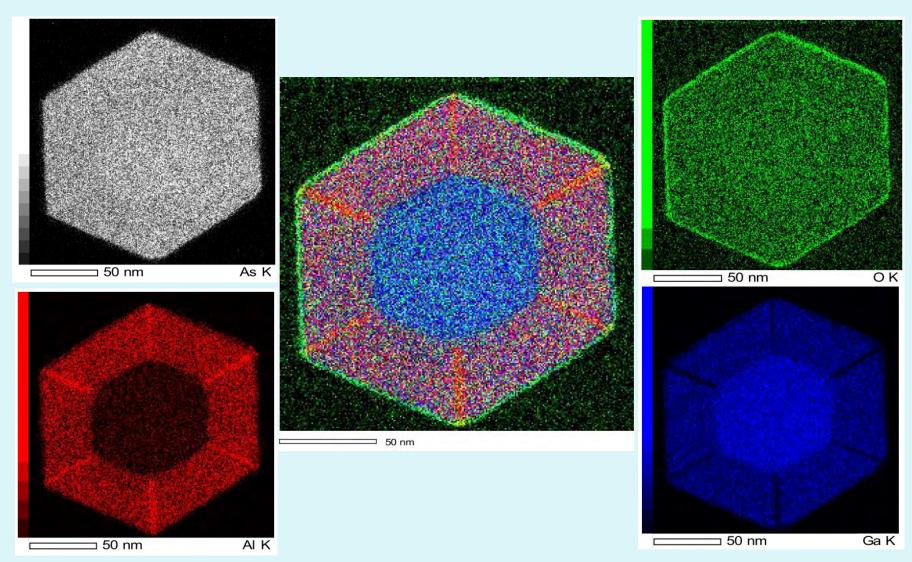
TEM characterization of III-V nanowires (HAADF STEM)



Dhaka et al., Nano Letters, 2013, 13 (8), pp 3581-3588

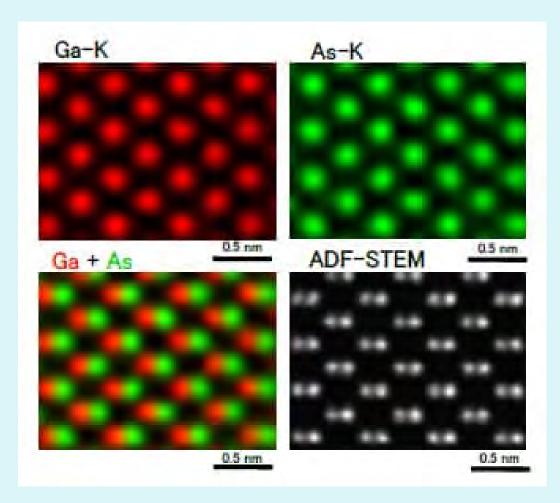
Elemental Mapping of cross-sectional GaAs nanowires

by analysing the X-ray signals generated in the sample – atomic composition can be analysed (EDX-spectroscopy)



Sample: Veer Dhaka, Aalto U.

Atomic resolution elemental analysis is also possible with modern high resolution microscopes..



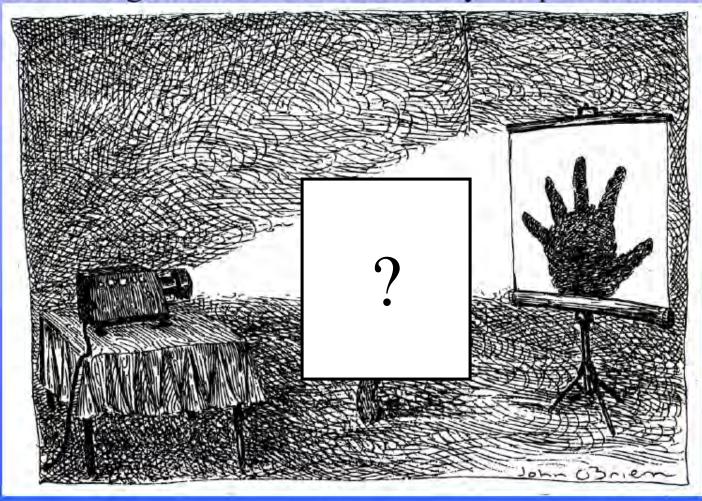
Atomic-level-resolution EDX elemental map of a gallium arsenide monocrystal <011>

3D tomography – Why important?

(Jani Seitsonen will give lecture on this topic later in the spring)

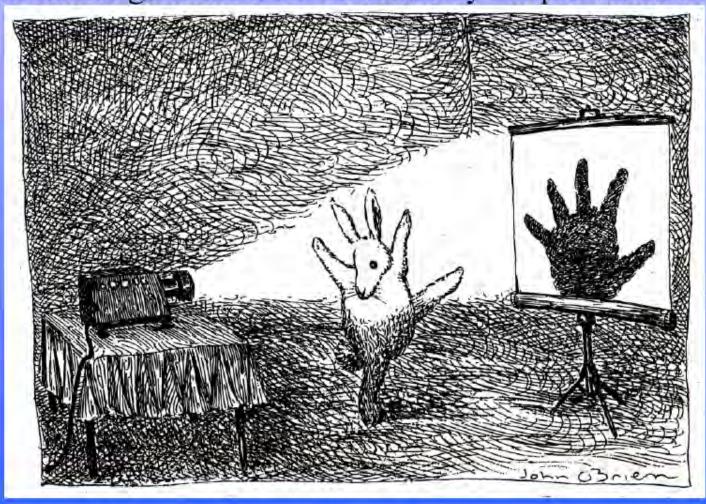
TEM image is projection from $3D \rightarrow 2D$

 Micrograph represents a projection image of the specimen. So features at different depths in the structure are all superimposed.
 Hence cannot generate a 3D structure by simple visual inspection.



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Another example of projection from 3D \rightarrow 2D



Another example of projection from $3D \rightarrow 2D$



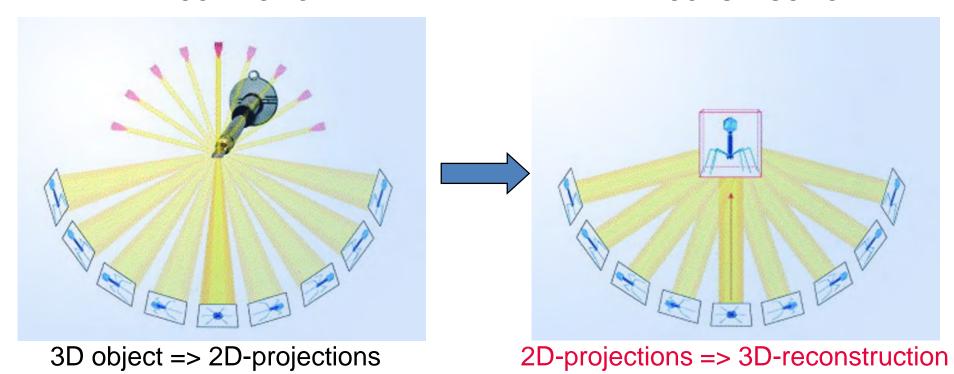


When 2D-projections are not enough: TOMOGRAPHY (or single particle reconstruction)

Principle of electron tomography:

DATA COLLECTION

RECONSTRUCTION



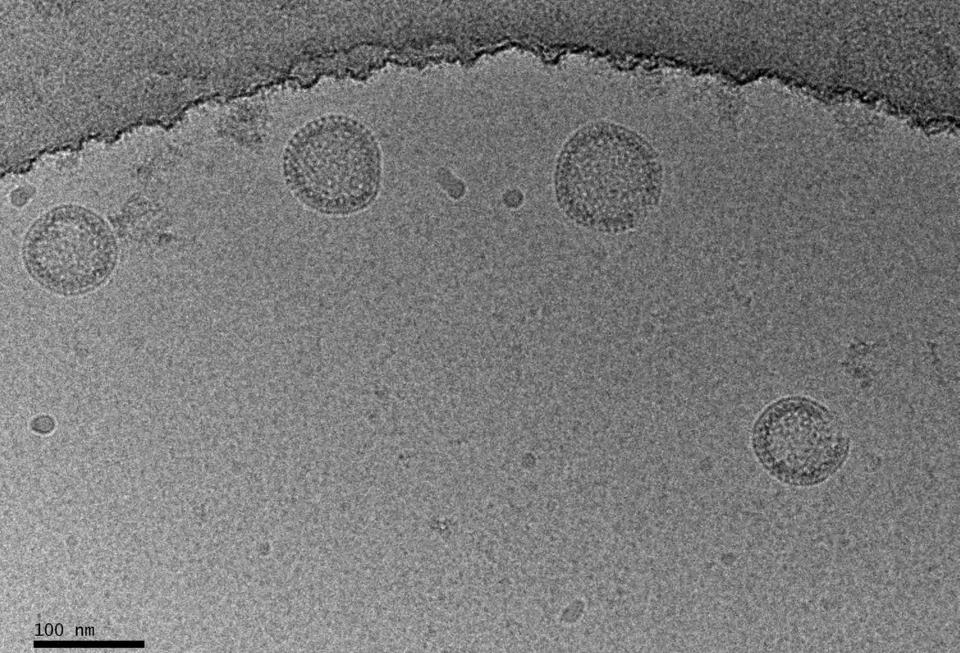
Cryo-Tomography

Case study: Cryo-EM structure of M-PMV VLPs

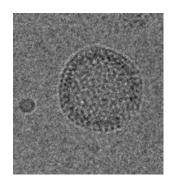
Sample: *in vitro* assembled Virus-Like Particles of Mason-Pfizer Monkey Virus

(Pasi Laurinmäki, Institute of Biotechnology University of Helsinki)

Normal TEM image is a projection from 3D specimen



3D cryo-EM: aligned tomographic tilt series

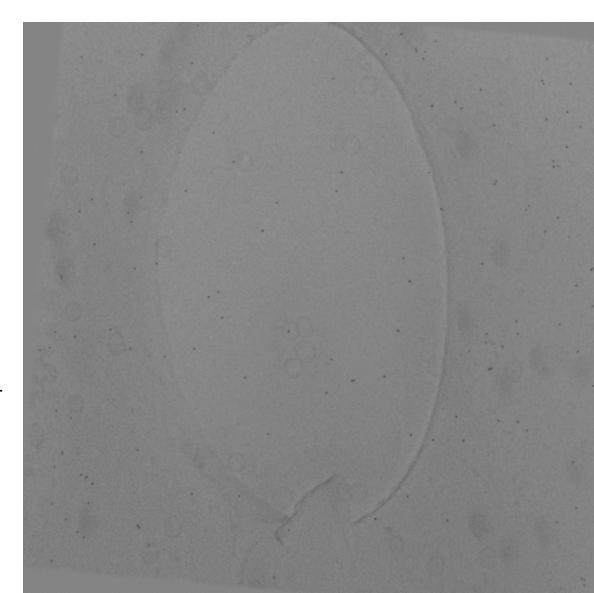


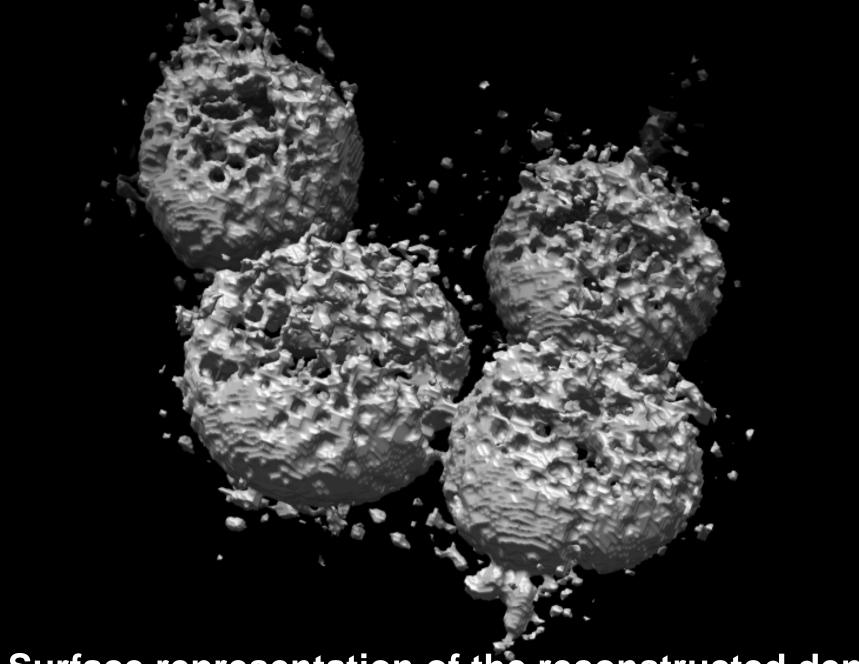
Low-dose series of *in vitro* assembled proCANC M-PMV particles

Diameter of the large round hole is about 2um

Dense dots are 10nm gold particles used as markers to align the images

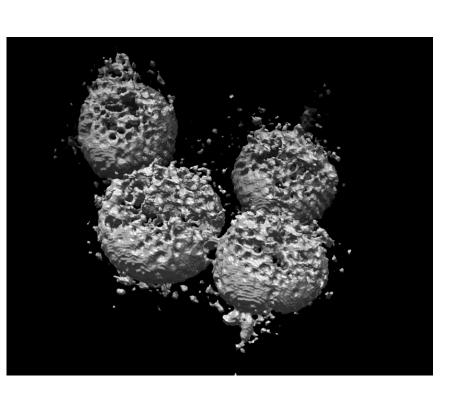
Then we just take images from -70 to + 70 degree tilt and do 3D recontruction

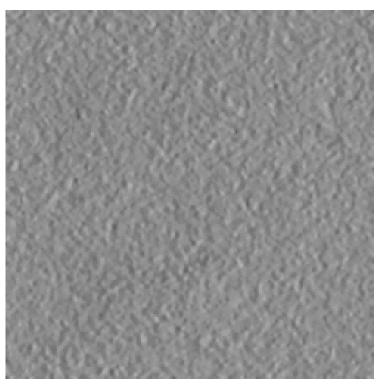


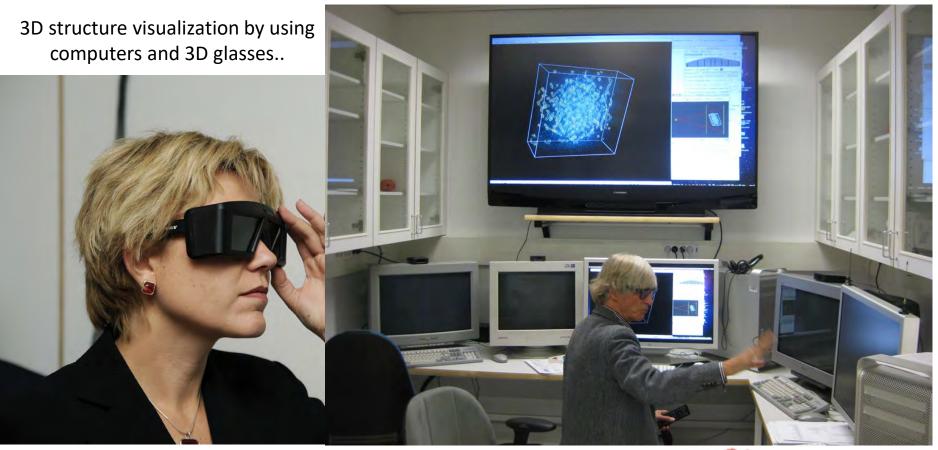


Surface representation of the reconstructed density

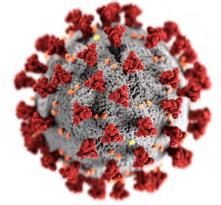
Serial sections through the reconstructed density







Using similar 3D imaging methods also the structure of the **SARS-CoV-2** virus was resolved (single particle reconstruction)



Sample preparation for TEM: THIN SPECIMENS

A major limitation of the TEM is we need thin specimens.

Methods to prepare thin specimens exist for almost all materials, and we talk about them specific lecture. But as a general rule, the thinning processes that we use do affect the specimens, changing both their structure and chemistry. So you need to be aware of the drawbacks of specimen preparation and learn to recognize the artifacts introduced by standard preparation methods.

Ultramicrotoming, ion milling, Focused ion beam, cryo sample preparation etc..

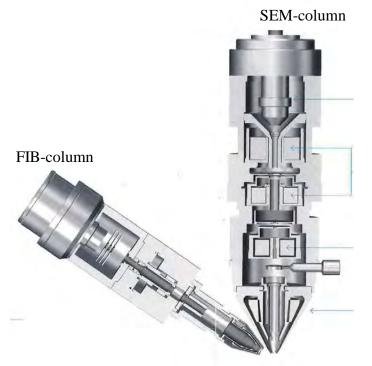




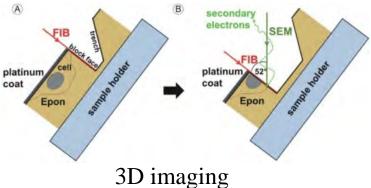


Planar Surface Preparation for SEM Cross Section Viewing

New Dual beam focused ion beam system in Nanomicrosopycenter (installation finnished by June 2019): Main applications TEM sample preparation, cross-section imaging and 3D imaging



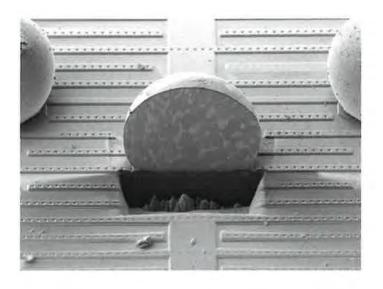






Here is the example of crosssection imagin: FIB column is used to cut the cross-section and SEM column for imaging

Example: FIB cross-section imaging from soldering tin particles





TEM sample preparation using Focused ion beam..

FIB is very usefull for hard materials thin cross-section sample preparation – after final polishing << 100 nm meter thick sample can be done

